This GIDEP PCN is to announce specifications change with the datasheet parameters for the following International Rectifier Part No. Note that this change is related to part specification only, and not due to a die physical change.

IRHLF77110 [2N7608T2]
100V, 100kRad, N-Channel TID Hardened MOSFET in a TO-205AF package

ELECTRICAL CHARACTERISTICS @ Tj = 25°C

Gfs [Forward Transconductance], change Vds test condition from 10V to 15V.

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS, including TABLE 1 (POST TOTAL DOSE IRRADATION)

Vsd [Diode Forward Voltage], change max limit from 1.4V to 1.2V.

Reference Datasheet - PD-97062